

4 CHANNEL LOW CAPACITANCE TVS DIODE ARRAY

Product Summary

V _{BR} (Min)	I _{PP} (Max)	C _T (Typ)
4.5V	45A	2.1pF

Description

The D5V0P4UR6SO is a high-performance device suitable for protecting four high-speed I/Os. These devices are assembled in SOT26 package and have high ESD surge capability and low capacitance.

Applications

Typically used at high-speed ports such as USB 2.0, IEEE1394 (Firewire[®], iLink™), Serial ATA, DVI, HDMI and PCI.





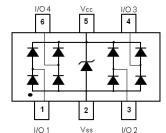
Top View

Features

- Low Clamping Voltage: Typical 7.5V at 12A 100ns, TLP, I/O to Vss; Typical 5.8V at 12A 100ns, TLP, Vcc to Vss
- IEC 61000-4-2 (ESD): Air ±30kV, Contact ±30kV
- IEC 61000-4-4 (EFT): ±80A (5/50ns)
- IEC 61000-4-5 (Lighting): 20A, I/O to V_{SS}; 45A, V_{CC} to V_{SS}
- TLP Dynamic Resistance: 0.15Ω, I/O to V_{SS}; 0.07Ω, V_{CC} to V_{SS}
- Low Channel Input Capacitance of 2.1pF Typical
- 4 Channels of ESD Protection
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

Mechanical Data

- Case: SOT26
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: See Schematic
- Terminals Finish Matte Tin Pleated Leadframe.
 Solderable per MIL-STD-202, Method 208 ³
- · Weight: 0.016 grams (Approximate)



Device Schematic

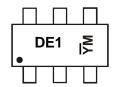
Ordering Information (Note 4)

Product	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per Reel
D5V0P4UR6SO-7	Standard	DE1	7	8	3,000/Tape & Reel

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information



DE1 = Product Type Marking Code

YM = Date Code Marking

Y = Year (ex: D = 2016)

M = Month (ex: 9 = September)

Note: "—" Represents Internal Code

Date Code Key

Year	20	16	20	17	20	18	20	19	20	20	20	21
Code	[)		E	I		(3	ŀ	1		
Month	Jan	Feb	Mar	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	Conditions
Peak Pulse Current, per IEC 61000-4-5	Ipp	20	А	I/O to V _{SS} , 8/20µs
Peak Pulse Current, per IEC 61000-4-5	Ipp	45	Α	V _{CC} to V _{SS} , 8/20µs
Peak Pulse Power, per IEC 61000-4-5	P _{PP}	180	W	I/O to V _{SS} , 8/20µs
Operating Supply Voltage (DC)	V_{DC}	3.6	V	V _{CC} to V _{SS}
ESD Protection – Contact Discharge, per IEC 61000-4-2	V _{ESD_CONTACT}	±30	kV	I/O to V _{SS} , V _{CC} to V _{SS}
ESD Protection – Air Discharge, per IEC 61000-4-2	V _{ESD_AIR}	±30	kV	I/O to V _{SS} , V _{CC} to V _{SS}
Operating Temperature	T _{OP}	-55 to +85	°C	_
Storage Temperature	T _{STG}	-55 to +150	°C	_

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Power Dissipation Typical (Note 5)	P_{D}	300	mW
Thermal Resistance, Junction to Ambient Typical (Note 5)	$R_{ heta JA}$	417	°C/W

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

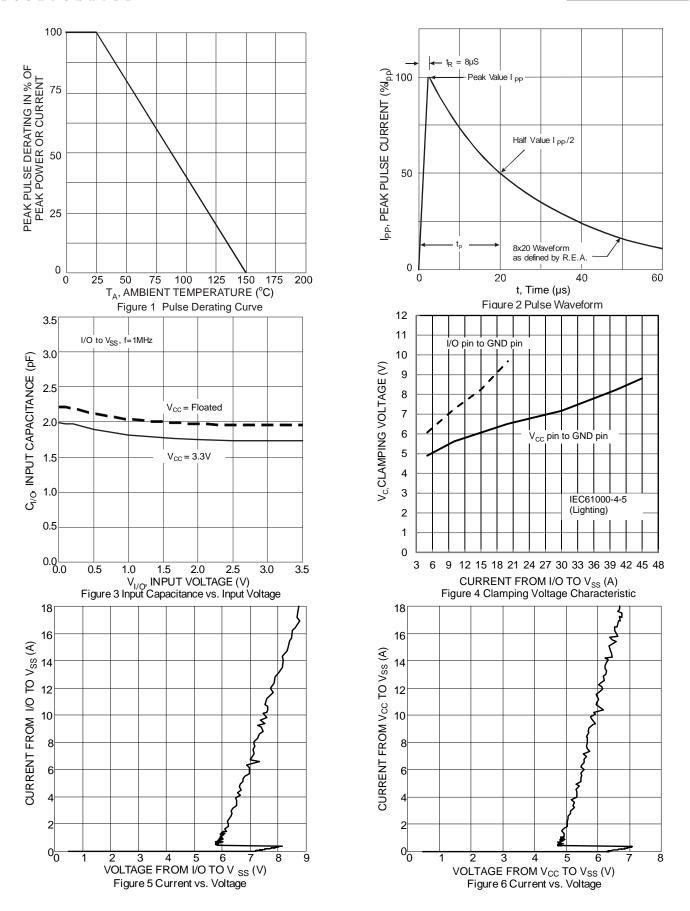
Characteristic	Symbol	Min	Тур	Max	Unit	Test Conditions
Reverse Working Voltage	V_{RWM}	_	_	3.3	V	V _{CC} to V _{SS}
Reverse Leakage Current (Note 6)	I _{LEAK}	_	_	5	μA	$V_{CC} = 3.3V$, V_{CC} to V_{SS}
Channel Leakage Current (Note 6)	I _{CH-LEAK}	_	_	1	μA	$V_{I/O}$ = 3.3V, I/O to V_{SS}
Reverse Breakdown Voltage	V_{BR}	4.5	_	7	V	I _{BR} = 1mA, V _{CC} to V _{SS}
Forward Clamping Voltage	VF	_	0.8	1.2	V	I _F = 15mA, V _{SS} to V _{CC}
Reverse Clamping Voltage (Note 7)	V	_	6	_	V	$I_{PP} = 5A$, I/O to V_{SS} , 8/20 μ s
Reverse Clamping Voltage (Note 7)	V _{C_5A}	_	4.8	_	V	I_{PP} = 5A, V_{CC} to V_{SS} , 8/20 μ s
ESD Clamping Voltage	V _{ESD}	_	7.5	_	V	TLP, 12A, t_P = 100ns, I/O to V_{SS}
L3D Clamping Voltage		_] v	TLP, 12A, $t_P = 100$ ns, V_{CC} to V_{SS}	
Dynamic Resistance	R _{DIF}	_	0.15		Ω	TLP, 12A, t_P = 100ns, I/O to V_{SS}
Dynamic Resistance		_	0.07	_	1 12	TLP, 12A, t_P = 100ns, V_{CC} to V_{SS}
Channel Innut Canaditanes	C _{I/O}	_	2.1	2.5	pF	$V_{I/O} = 1.65V$, $V_{CC} = 3.3V$, $f = 1MHz$
Channel Input Capacitance		_	2.4	3.0	pF	$V_{I/O} = 1.65V$, $V_{CC} = $ floated, $f = 1MHz$
			0.05		pF	$V_{SS} = 0V$, I/O = 1.65V, $V_{CC} = 3.3V$, f = 1MHz,
Variation of Channel Input Capacitance	ACuo.		0.05	_	рг	I/O_x to $V_{SS} - I/O_y$ to V_{SS}
variation of original input dapacitance	$\Delta C_{I/O}$	_	0.04	_	pF	$V_{SS} = 0V$, $I/O = 1.65V$, $V_{CC} = floated$, $f = 1MHz$, I/O_x to $V_{SS} - I/O_y$ to V_{SS}

Notes:

- 5. Device mounted on FR-4 PCB pad layout (2oz copper) as shown on Diodes, Inc. website at http://www.diodes.com/package-outlines.html.
- 6. Short duration pulse test used to minimize self-heating effect.
- 7. Clamping voltage value is based on an 8x20µs peak pulse current (IPP) waveform.



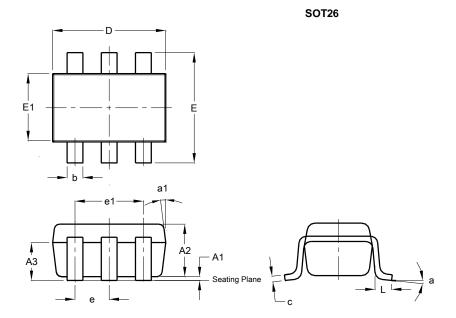






Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

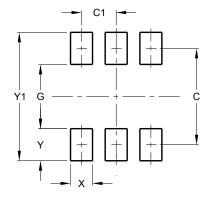


SOT26						
Dim	Min	Max	Тур			
A1	0.013	0.10	0.05			
A2	1.00	1.30	1.10			
А3	0.70	0.80	0.75			
b	0.35	0.50	0.38			
С	0.10	0.20	0.15			
D	2.90	3.10	3.00			
е	-	_	0.95			
e1	-	_	1.90			
Е	2.70	3.00	2.80			
E1	1.50	1.70	1.60			
L	0.35	0.55	0.40			
а	_	_	8°			
a1	_	_	7°			
All Dimensions in mm						

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT26



Dimensions	Value (in mm)
С	2.40
C1	0.95
G	1.60
Х	0.55
Υ	0.80
Y1	3.20



IMPORTANT NOTICE

DIODES INCORPORATED MAKES NO WARRANTY OF ANY KIND, EXPRESS OR IMPLIED, WITH REGARDS TO THIS DOCUMENT, INCLUDING, BUT NOT LIMITED TO, THE IMPLIED WARRANTIES OF MERCHANTABILITY AND FITNESS FOR A PARTICULAR PURPOSE (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION).

Diodes Incorporated and its subsidiaries reserve the right to make modifications, enhancements, improvements, corrections or other changes without further notice to this document and any product described herein. Diodes Incorporated does not assume any liability arising out of the application or use of this document or any product described herein; neither does Diodes Incorporated convey any license under its patent or trademark rights, nor the rights of others. Any Customer or user of this document or products described herein in such applications shall assume all risks of such use and will agree to hold Diodes Incorporated and all the companies whose products are represented on Diodes Incorporated website, harmless against all damages.

Diodes Incorporated does not warrant or accept any liability whatsoever in respect of any products purchased through unauthorized sales channel. Should Customers purchase or use Diodes Incorporated products for any unintended or unauthorized application, Customers shall indemnify and hold Diodes Incorporated and its representatives harmless against all claims, damages, expenses, and attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized application.

Products described herein may be covered by one or more United States, international or foreign patents pending. Product names and markings noted herein may also be covered by one or more United States, international or foreign trademarks.

This document is written in English but may be translated into multiple languages for reference. Only the English version of this document is the final and determinative format released by Diodes Incorporated.

LIFE SUPPORT

Diodes Incorporated products are specifically not authorized for use as critical components in life support devices or systems without the express written approval of the Chief Executive Officer of Diodes Incorporated. As used herein:

- A. Life support devices or systems are devices or systems which:
 - 1. are intended to implant into the body, or
 - 2. support or sustain life and whose failure to perform when properly used in accordance with instructions for use provided in the labeling can be reasonably expected to result in significant injury to the user.
- B. A critical component is any component in a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or to affect its safety or effectiveness.

Customers represent that they have all necessary expertise in the safety and regulatory ramifications of their life support devices or systems, and acknowledge and agree that they are solely responsible for all legal, regulatory and safety-related requirements concerning their products and any use of Diodes Incorporated products in such safety-critical, life support devices or systems, notwithstanding any devices- or systems-related information or support that may be provided by Diodes Incorporated. Further, Customers must fully indemnify Diodes Incorporated and its representatives against any damages arising out of the use of Diodes Incorporated products in such safety-critical, life support devices or systems.

Copyright © 2016, Diodes Incorporated

www.diodes.com